# 74LV165A-Q100

# 8-bit parallel-in/serial-out shift register

Rev. 3 — 28 March 2014

**Product data sheet** 

## 1. General description

The 74LV165A-Q100 is an 8-bit parallel-load or serial-in shift register with complementary serial outputs (Q7 and  $\overline{\text{Q7}}$ ) available from the last stage. When the parallel-load input ( $\overline{\text{PL}}$ ) is LOW, parallel data from the inputs D0 to D7 are loaded into the register asynchronously. When input  $\overline{\text{PL}}$  is HIGH, data enters the register serially at the input DS. It shifts one place to the right (Q0  $\rightarrow$  Q1  $\rightarrow$  Q2, etc.) with each positive-going clock transition. This feature allows parallel-to-serial converter expansion by tying the output Q7 to the input DS of the succeeding stage. The clock input is a gate-OR structure which allows one input to be used as an active LOW clock enable input ( $\overline{\text{CE}}$ ) input. The pin assignment for the inputs CP and  $\overline{\text{CE}}$  is arbitrary and can be reversed for layout convenience. The LOW-to-HIGH transition of the input  $\overline{\text{CE}}$  should only take place while CP HIGH for predictable operation.

Schmitt-trigger action at all inputs, makes the circuit tolerant for slower input rise and fall times. It is fully specified for partial-power-down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output, preventing the damaging current backflow through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 3) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 3)
  - ◆ Specified from -40 °C to +85 °C
- Wide supply voltage range from 2.0 V to 5.5 V
- Synchronous parallel-to-serial applications
- Synchronous serial input for easy expansion
- Latch-up performance exceeds 250 mA
- CMOS LOW power consumption
- 5.5 V tolerant inputs/outputs
- Direct interface with TTL levels (2.7 V to 3.6 V)
- Power-down mode
- Complies with JEDEC standards:
  - JESD8-5 (2.3 V to 2.7 V)
  - ◆ JESD8B/JESD36 (2.7 V to 3.6 V)
  - ◆ JESD8-1A (4.5 V to 5.5 V)
- ESD protection:
  - MIL-STD-833, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - ♦ MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

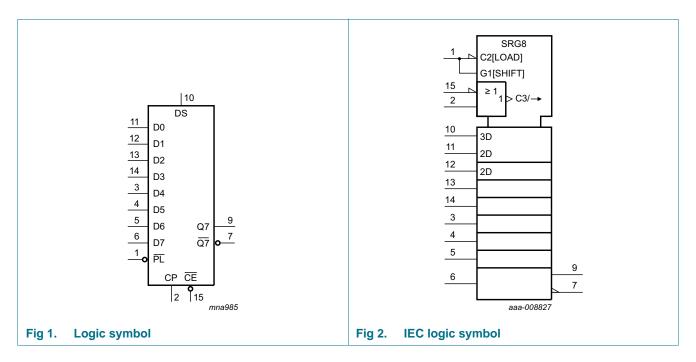


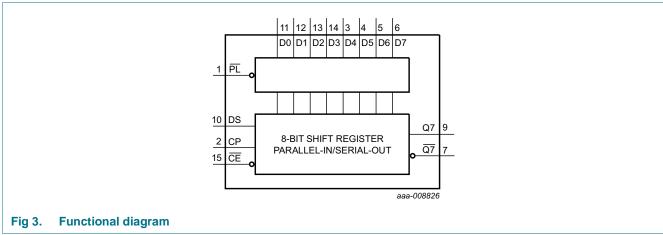
## 3. Ordering information

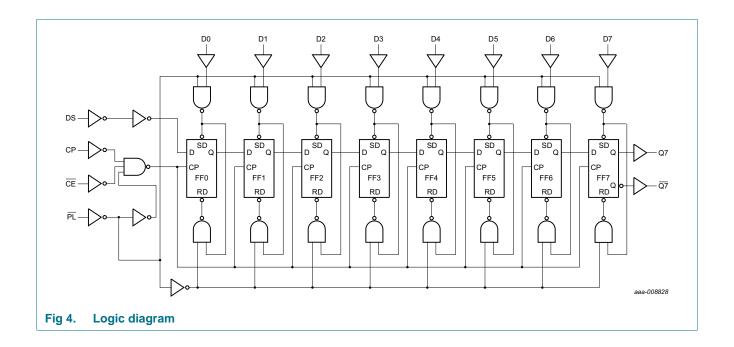
Table 1. Ordering information

Type number	Package						
	Temperature range Name Description						
74LV165AD-Q100	–40 °C to +85 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1			
74LV165APW-Q100	–40 °C to +85 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1			

## 4. Functional diagram

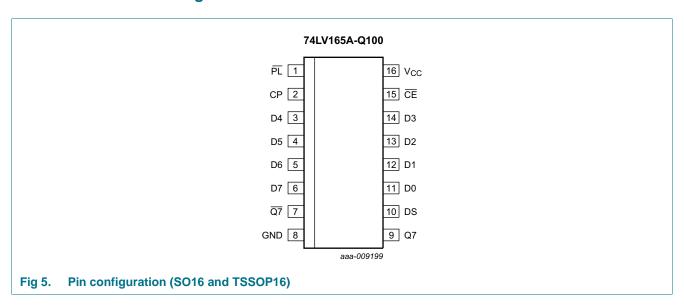






## 5. Pinning information

### 5.1 Pinning



## 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
PL	1	parallel enable input (active LOW)
СР	2	clock input (LOW-to-HIGH edge-triggered)
Q7	7	complementary serial output from the last stage
GND	8	ground (0 V)
Q7	9	serial output from the last stage
DS	10	serial data input
D0 to D7	11, 12, 13, 14, 3, 4, 5, 6	parallel data inputs
CE	15	clock enable input (active LOW)
V <sub>CC</sub>	16	positive supply voltage

## 6. Functional description

Table 3. Function table[1]

Operating modes	Inputs	Inputs				Qn regi	Qn registers		Output	
	PL	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7	Q7	
parallel load	L	Х	Х	Х	L	L	L to L	L	Н	
	L	Х	Х	Х	Н	Н	H to H	Н	L	
serial shift	Н	L	1	I	X	L	q0 to q5	q6	<del>q</del> 6	
	Н	L	1	h	X	Н	q0 to q5	q6	<del>q</del> 6	
	Н	<b>↑</b>	L	I	X	L	q0 to q5	q6	<del>q</del> 6	
	Н	1	L	h	X	Н	q0 to q5	q6	<del>q</del> 6	
hold "do nothing"	Н	Н	Х	Х	X	q0	q1 to q6	q7	<del>q</del> 7	
	Н	Х	Н	Х	X	q0	q1 to q6	q7	<del>q</del> 7	

#### [1] H = HIGH voltage level;

h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

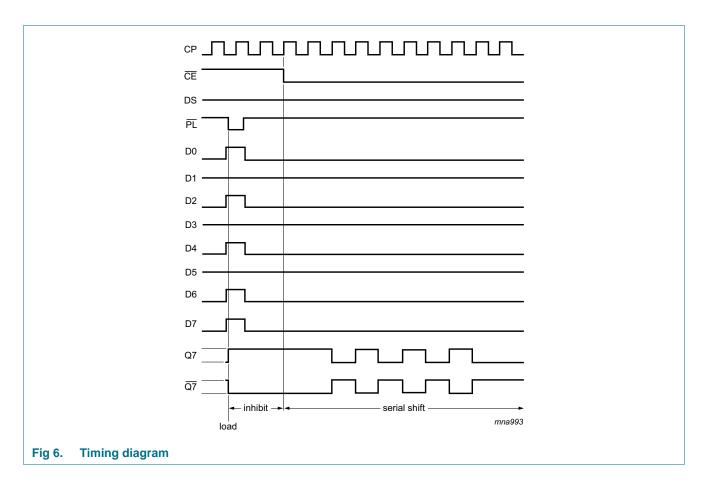
L = LOW voltage level;

I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

q = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

X = don't care;

 $\uparrow$  = LOW-to-HIGH clock transition.



## 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)[1]

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-	-20	mA
VI	input voltage		-0.5	+7	V
I <sub>OK</sub>	output clamping current	$V_O > V_{CC}$ or $V_O < 0$	-	±50	mA
Vo	output voltage		-0.5	V <sub>CC</sub> + 0.5	V
		power-down mode	-0.5	+7	V
Io	output current	0 V < V <sub>O</sub> < V <sub>CC</sub>	-	±25	mA
I <sub>CC</sub>	supply current		-	+50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$			
		SO16 package	-	500	mW
		TSSOP16 package	_	500	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CC}$	supply voltage		2.0	-	5.5	V
V <sub>I</sub>	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	0	-	200	ns/V
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	0	-	100	ns/V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0	-	20	ns/V

<sup>[2]</sup> Ptot derates linearly with 8 mW/K above 70 °C.

<sup>[3]</sup> P<sub>tot</sub> derates linearly with 5.5 mW/K above 60 °C.

## 9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T <sub>amb</sub>	= -40 °C 1	to +85 °C	Unit
			Min	Тур	Max	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.7V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.7V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.7V <sub>CC</sub>	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.3V <sub>CC</sub>	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.3V <sub>CC</sub>	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.3V <sub>CC</sub>	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_{O} = -50 \mu A$ ; $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$	V <sub>CC</sub> - 0.1	-	-	V
		$I_{O} = -2.0 \text{ mA}; V_{CC} = 2.3 \text{ V}$	2.0	-	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.48	-	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.8	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$				
		$I_O = 50 \mu A$ ; $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$	-	-	0.10	V
		$I_{O} = 2.0 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.40	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V
		I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 4.5 V	-	-	0.55	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	±0.01	±1	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 5.5 \text{ V}$ ; $V_{CC} = 0.0 \text{ V}$	-	±0.05	±5	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	0.2	20	μΑ
Cı	input capacitance		-	3.0	-	pF

# 10. Dynamic characteristics

**Dynamic characteristics** Table 7.

GND (ground = 0 V); for test circuit, see Figure 12

Symbol	Parameter	Conditions		T <sub>amb</sub>	= -40 °C to	+85 °C	Unit
				Min	Typ[1]	Max	
t <sub>pd</sub>	propagation delay	$\overline{\text{CE}}$ , CP to Q7, $\overline{\text{Q7}}$ ; C <sub>L</sub> = 15 pF; see <u>Figure 7</u> and <u>Figure 8</u>	[2]				
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	1.0	11.0	22.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	1.0	7.5	18.0	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	1.0	5.5	11.5	ns
		PL to Q7, Q7; C <sub>L</sub> = 15 pF; see Figure 8					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	1.0	11.5	23.5	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	1.0	8.0	18.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	1.0	5.5	11.5	ns
		D7 to Q7, $\overline{Q7}$ ; $C_L = 15 \text{ pF}$ ; see Figure 9					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	1.0	12.0	24.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	1.0	8.5	16.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	1.0	6.0	10.5	ns
		CE, CP to Q7, Q7; see Figure 7 and Figure 8					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	1.0	13.0	26.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	1.0	9.0	21.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	1.0	6.1	13.5	ns
		PL to Q7, Q7; see Figure 8					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	1.0	14.0	28.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	1.0	10.0	22.0	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	1.0	6.5	13.5	ns
		D7 to Q7, Q7; see Figure 9					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	1.0	14.0	28.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	1.0	10.0	20	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	1.0	6.5	12.5	ns
t <sub>W</sub>	pulse width	CP input HIGH to LOW; see Figure 7					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	9.0	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	7.0	-	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	4.0	-	-	ns
		PL input LOW; see Figure 8					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	13.0	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	9.0	-	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	6.0	-	-	ns
t <sub>rec</sub>	recovery time	PL to CP, CE; see Figure 8					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	8.5	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	<u>[4]</u>	6.0	-	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	4.0	-	-	ns

**Table 7. Dynamic characteristics** ...continued GND (ground = 0 V); for test circuit, see <u>Figure 12</u>

Symbol	Parameter	rameter Conditions		T <sub>amb</sub>	= -40 °C to	+85 °C	Unit
			Min	Typ[1]	Max		
t <sub>su</sub>	set-up time	DS to CP, CE; see Figure 10					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	6.0	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	4.0	-	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	<u>[5]</u>	7.0	-	-	ns
		CE to CP, CP to CE; see Figure 10					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	7.0	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	5.0	-	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	<u>[5]</u>	3.5	-	-	ns
		D7 to PL; see Figure 11					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	12	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	8.5	-	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	5.0	-	-	ns
t <sub>h</sub>	hold time	DS to CP, CE; PL to CP, CE; see Figure 10					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	0	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	0	-	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	0.5	-	-	ns
		Dn to PL; see Figure 11					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	0.5	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	0.5	-	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	1.0	-	-	ns
f <sub>max</sub>	maximum	CP input; C <sub>L</sub> = 15 pF; see Figure 7					
	frequency	V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	45	80	-	MHz
		V <sub>CC</sub> = 3.0 V to 3.6 V	[4]	50	115	-	MHz
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	90	165	-	MHz
		CP input; see Figure 7					
		V <sub>CC</sub> = 2.3 V to 2.7 V	[3]	35	65	-	MHz
		V <sub>CC</sub> = 3.0 V to 3.6 V	<u>[4]</u>	50	90	-	MHz
		V <sub>CC</sub> = 4.5 V to 5.5 V	[5]	85	125	-	MHz

**Table 7. Dynamic characteristics** ...continued GND (ground = 0 V); for test circuit, see Figure 12

Symbol	mbol Parameter Conditions		T <sub>amb</sub> =	⊦85 °C	Unit	
			Min	Typ[1]	Max	
C <sub>PD</sub>	power dissipation capacitance	$V_1 = GND \text{ to } V_{CC}; V_{CC} = 3.3 \text{ V}$ [6]	-	24	-	pF

- [1] Typical values are measured at  $T_{amb}$  = 25 °C and nominal  $V_{CC}$ .
- [2]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .
- [3] Typical values are measured at  $V_{CC}$  = 2.5 V.
- [4] Typical values are measured at  $V_{CC} = 3.3 \text{ V}$ .
- [5] Typical values are measured at  $V_{CC}$  = 5.0 V.
- [6]  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o) (P_D \text{ in } \mu \text{W})$ , where:  $f_i = \text{input frequency in MHz}$ ;

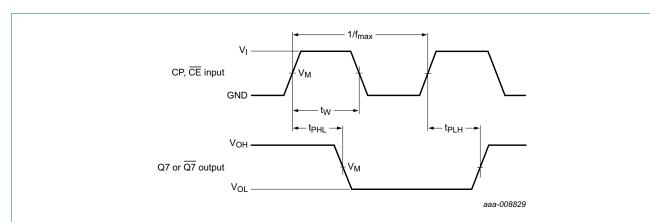
f<sub>o</sub> = output frequency in MHz;

 $\Sigma (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs};$ 

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V.

### 11. Waveforms



Measurement points are given in Table 8.

The changing to output assumes that internal Q6 is opposite state from Q7.

Fig 7. Clock pulse (CP) and clock enable (CE) to output (Q7 or Q7) propagation delays, clock pulse width and maximum clock frequency

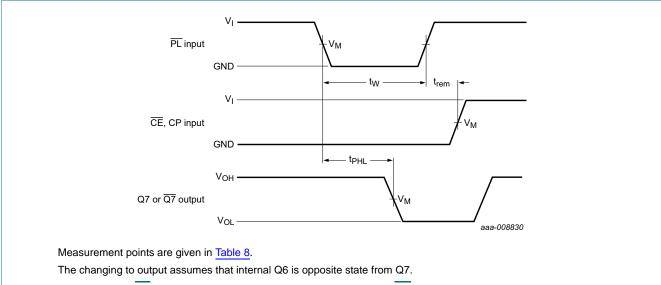
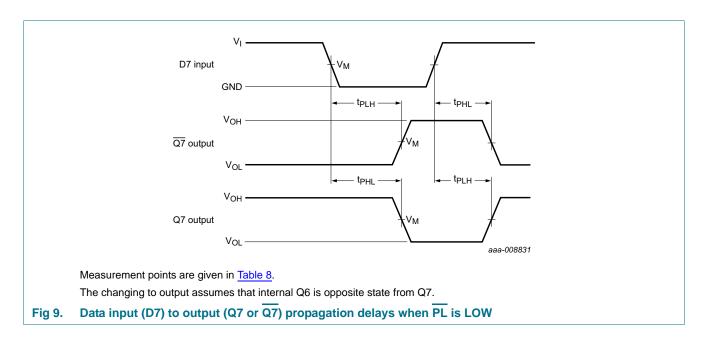
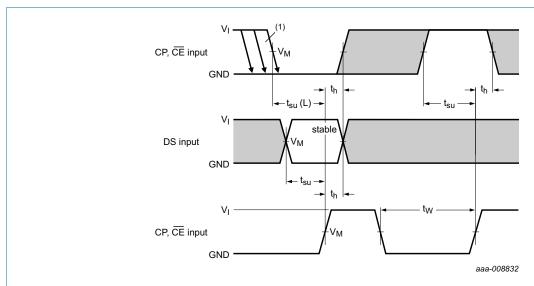


Fig 8. Parallel load (PL) pulse width, parallel load to output (Q7 or Q7) propagation delays, parallel load to clock (CP) and clock enable (CE) recovery time





Measurement points are given in Table 8.

(1) CE may change only from HIGH-to-LOW while CP is LOW. The shaded areas indicate when the input is permitted to change for predictable output performance.

Fig 10. Set-up and hold times

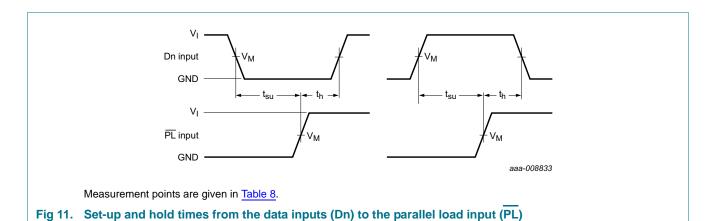
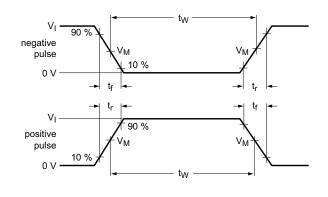
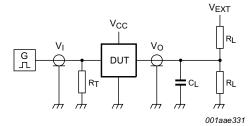


Table 8. Measurement points

Supply voltage	Input	Output
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>
2.0 V to 5.5 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>





Test data is given in Table 9.

Definitions for test circuit:

 $R_L$  = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

 $V_{EXT}$  = External voltage for measuring switching times.

Fig 12. Test circuit for measuring switching times

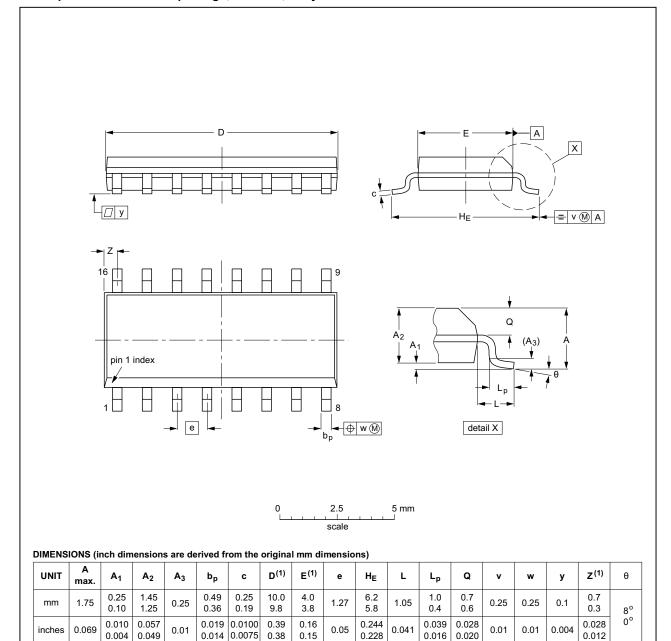
Table 9. Test data

Supply voltage	Input		Load	V <sub>EXT</sub>	
	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	C <sub>L</sub> R <sub>L</sub>		t <sub>PHL</sub> , t <sub>PLH</sub>
2.0 V to 5.5 V	V <sub>CC</sub>	3.0 ns	50 pF, 15 pF	1 kΩ	open

## 12. Package outline

### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	1920E DATE	
SOT109-1	076E07	MS-012			<del>99-12-27</del> 03-02-19	

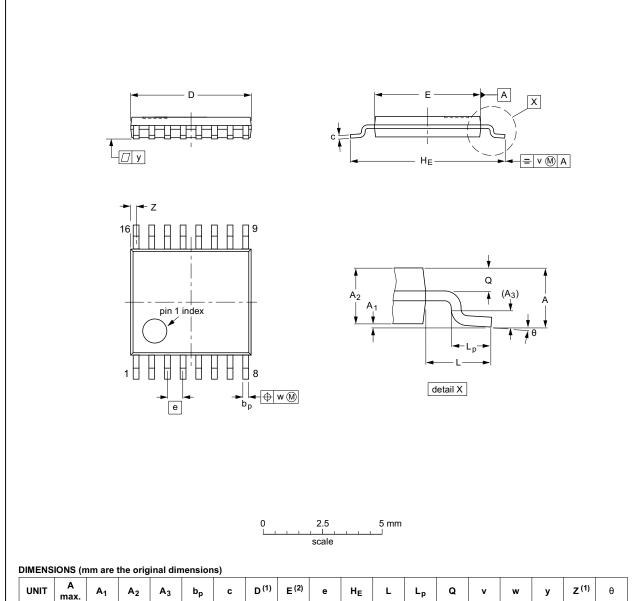
Fig 13. Package outline SOT109-1 (SO16)

74LV165A\_Q100

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	C	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

JEITA	PROJECTION	ISSUE DATE
		<del>99-12-27</del> 03-02-18

Fig 14. Package outline SOT403-1 (TSSOP16)

74LV165A\_Q100

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## 13. Abbreviations

### Table 10. Abbreviations

Acronym	Description				
CMOS	Complementary Metal-Oxide Semiconductor				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
HBM	Human Body Model				
MIL	Military				
MM	Machine Model				
TTL	Transistor-Transistor Logic				

# 14. Revision history

### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LV165A_Q100 v.3	20140328	Product data sheet	-	74LV165A_Q100 v.2
Modifications:	Minimum limit characteristic	$t V_{OH}$ for $V_{CC} = 4.5 V$ corrected $s''$	d from 3.0 V to 3.8 V	(errata) in Table 6 "Static
74LV165A_Q100 v.2	20140219	Product data sheet	-	74LV165A_Q100 v.1
Modifications:	Typo correcte	d in Table 2 "Pin description"		
74LV165A_Q100 v.1	20131021	Product data sheet	-	-

## 15. Legal information

#### 15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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